

Vishay Semiconductors

Small Signal Fast Switching Diodes



FEATURES

- Silicon epitaxial planar diodes
- Electrical data identical with the devices 1N4148 and 1N4448 respectively



- Quadro Melf package
- AEC-Q101 qualified

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

• Extremely fast switches

MECHANICAL DATA

Case: QuadroMELF SOD-80
Weight: approx. 34mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

PARTS TABLE						
PART	TYPE DIFFERENTIATION	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS	
LS4148	$V_F = \text{max. } 1000 \text{ mV at } I_F = 50 \text{ mA}$	LS4148-GS18 or LS4148-GS08	-	Single diode	Tape and reel	
LS4448	$V_F = \text{max. } 1000 \text{ mV at } I_F = 100 \text{ mA}$	LS4448GS18 or LS4448GS08	-	Single diode	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		V _{RRM}	100	V	
Reverse voltage		V _R	75	V	
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α	
Repetitive peak forward current		I _{FRM}	500	mA	
Forward continuous current		I _F	300	mA	
Average forward current	V _R = 0	I _{F(AV)}	150	mA	
Power dissipation		P _{tot}	500	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air	junction to ambient air On PC board 50 mm x 5.0 mm x 1.6 mm R _{thJA}		300	K/W	
Junction temperature		Tj	175	°C	
Storage temperature range		T _{sta}	- 65 to + 175	°C	



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 5 mA	LS4448	V _F	620		720	mV
Forward voltage	I _F = 50 mA	LS4148	V _F		860	1000	mV
	I _F = 100 mA	LS4448	V _F		930	1000	mV
	V _R = 20 V		I _R			25	nA
Reverse current	V _R = 20 V, T _j = 150 °C		I _R			50	μΑ
	V _R = 75 V		I _R			5	μΑ
Breakdown voltage $ \begin{array}{c} I_{R} = 100 \; \mu\text{A, } t_{p}\text{/T} = 0.01, \\ t_{p} = 0.3 \; \text{ms} \end{array} $			V _(BR)	100			V
Diode capacitance	V _R = 0, f = 1 MHz, V _{HF} = 50 mV		C _D			4	pF
	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA}$		t _{rr}			8	ns
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $i_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$		t _{rr}			4	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

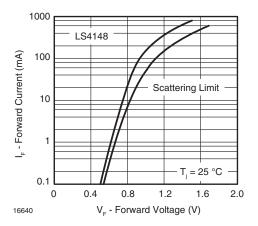


Fig. 1 - Forward Current vs. Forward Voltage

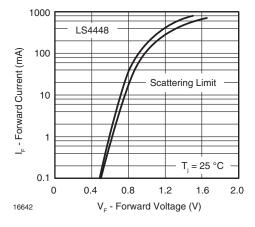


Fig. 2 - Forward Current vs. Forward Voltage

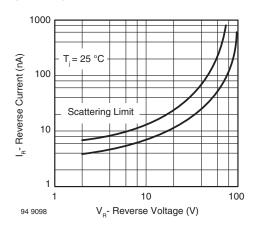


Fig. 3 - Reverse Current vs. Reverse Voltage

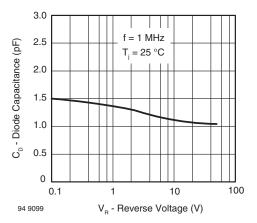
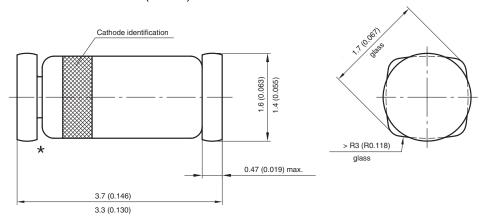


Fig. 4 - Diode Capacitance vs. Reverse Voltage

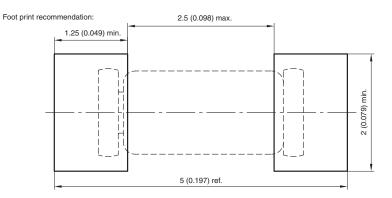


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PACKAGE DIMENSIONS in millimeters (inches): QuadroMELF SOD-80



★ The gap between plug and glass can be either on cathode or anode side



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